

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO247 plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{j(max)} = 150\text{ }^{\circ}\text{C}$).

2. Features and benefits

- High junction operating temperature capability ($T_{j(max)} = 150\text{ }^{\circ}\text{C}$)
- Very high current surge capability
- Planar passivated for voltage ruggedness and reliability
- High thermal cycling performance
- High voltage capability

3. Applications

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control
- Uninterruptible Power Supply (UPS)
- Solid State Relay (SSR)
- Traction battery charging

4. Quick reference data

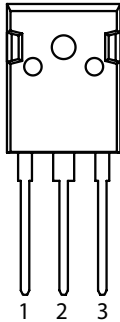

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_{mb} \leq 137\text{ }^{\circ}\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3		30	A
I_{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25\text{ }^{\circ}\text{C}$; $t_p = 10\text{ ms}$; Fig 4 ; Fig 5		400	A
		half sine wave; $T_{j(init)} = 25\text{ }^{\circ}\text{C}$; $t_p = 8.3\text{ ms}$		440	A
T_j	junction temperature			150	$^{\circ}\text{C}$

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 7		6	-	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; Fig. 9		-	-	60	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; Fig. 10		-	1.10	1.30	V
		I _T = 60 A; T _j = 25 °C; Fig. 10		-	1.30	1.50	V
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 150 °C; exponential waveform; gate open circuit		1000	-	-	V/μs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
3	G	gate		
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN30W-800T	TO247	TYN30W-800TQ	Tube	30	TO247E	18-Jun-2021

7. Marking

Table 4. Marking codes

Type number	Marking codes
TYN30W-800T	TYN30W 800T

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
V_{RRM}	repetitive peak reverse voltage			800	V
$I_{\text{T(AV)}}$	average on-state current	half sine wave; $T_{\text{mb}} \leq 137\text{ }^{\circ}\text{C}$;		19	A
$I_{\text{T(RMS)}}$	RMS on-state current	half sine wave; $T_{\text{mb}} \leq 137\text{ }^{\circ}\text{C}$; Fig. 1 ; Fig. 2 ; Fig. 3		30	A
I_{TSM}	non-repetitive peak on-state current	half sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$; $t_{\text{p}} = 10\text{ ms}$; Fig 4 ; Fig 5		400	A
		half sine wave; $T_{\text{j(init)}} = 25\text{ }^{\circ}\text{C}$; $t_{\text{p}} = 8.3\text{ ms}$		440	A
I^2t	I^2t for fusing	$t_{\text{p}} = 10\text{ ms}$; sine-wave pulse		800	A^2s
di_{T}/dt	rate of rise of on-state current	$I_{\text{G}} = 30\text{ mA}$		200	$\text{A}/\mu\text{s}$
I_{GM}	peak gate current			5	A
V_{GM}	peak gate voltage			5	V
V_{RGM}	peak reverse gate voltage			7	V
P_{GM}	peak gate power			20	W
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period		0.5	W
T_{stg}	storage temperature			-40 to 150	$^{\circ}\text{C}$
T_{j}	junction temperature			150	$^{\circ}\text{C}$

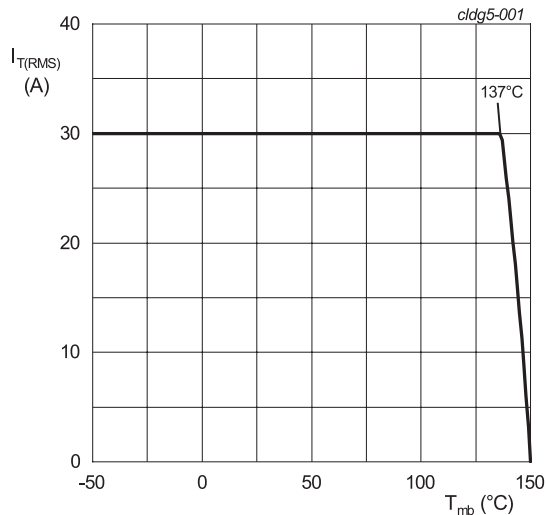
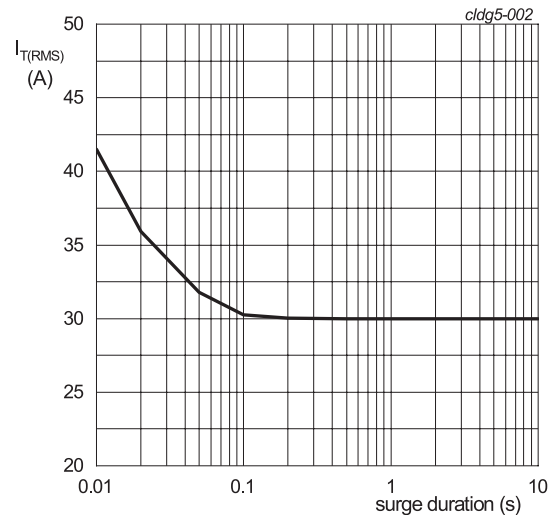
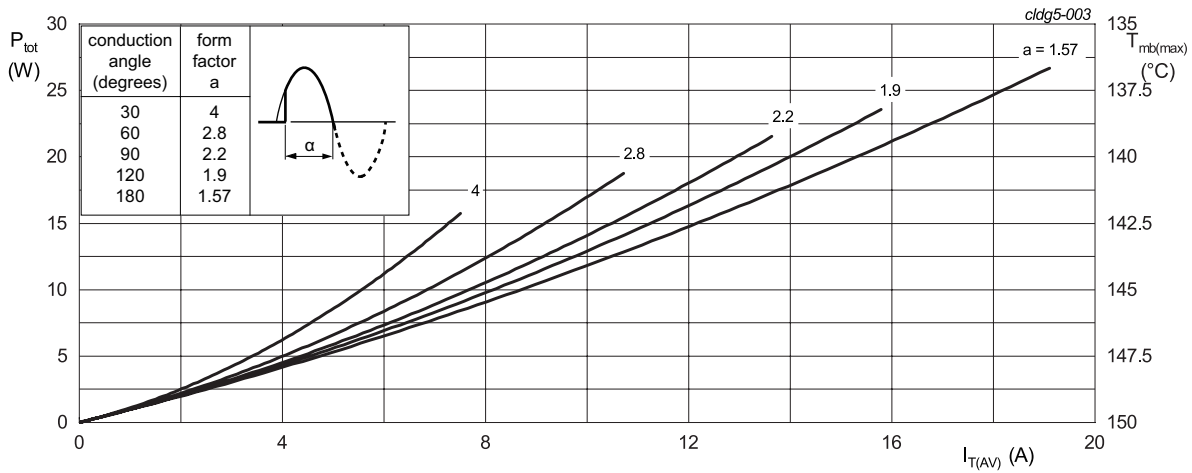


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values



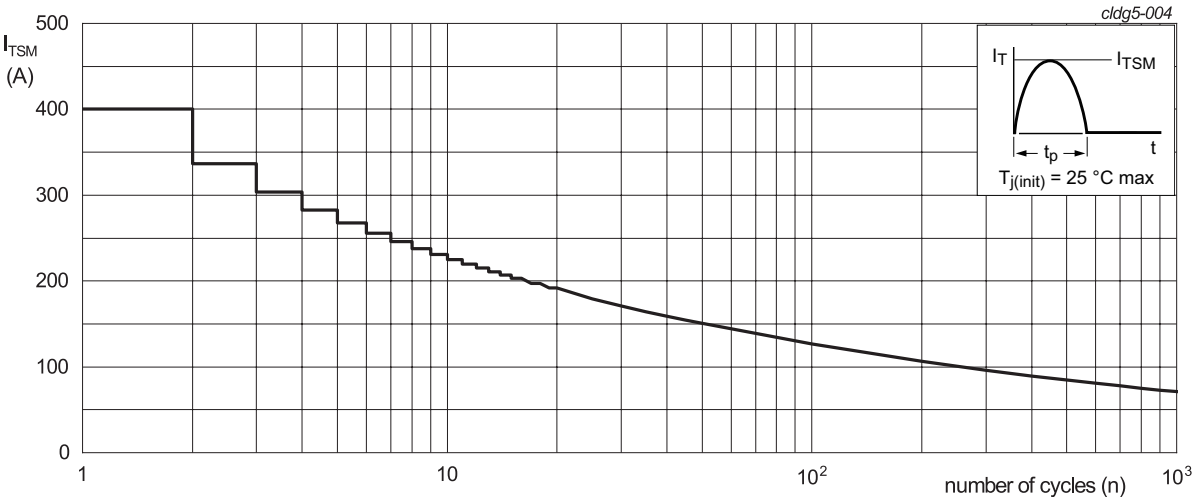
$f = 50\text{ Hz}$; $T_{\text{mb}} = 137\text{ }^{\circ}\text{C}$

Fig. 2. RMS on-state current as a function of surge duration; maximum values



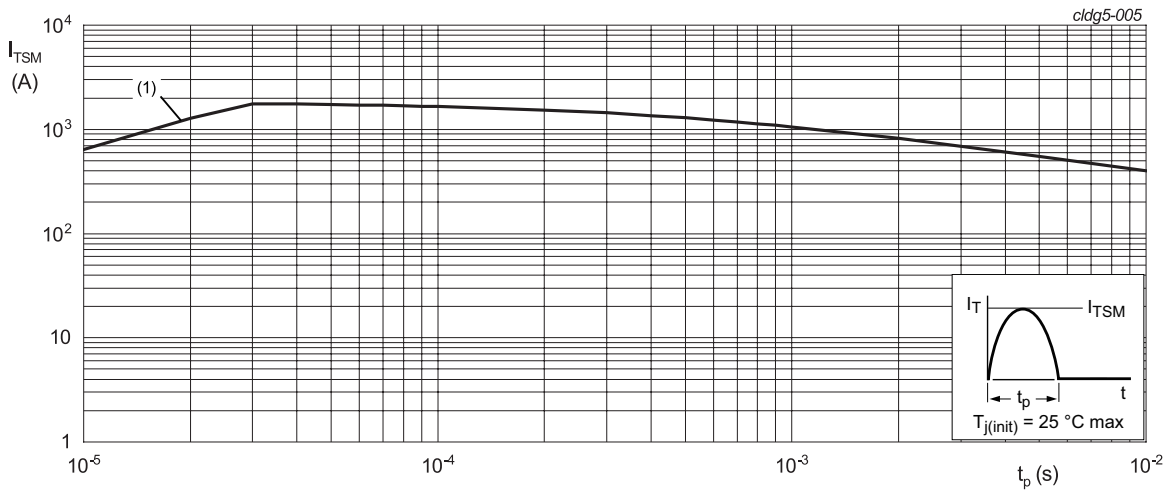
α = conduction angle
 a = form factor = $I_{T(RMS)} / I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values



$f = 50\text{ Hz}$

Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



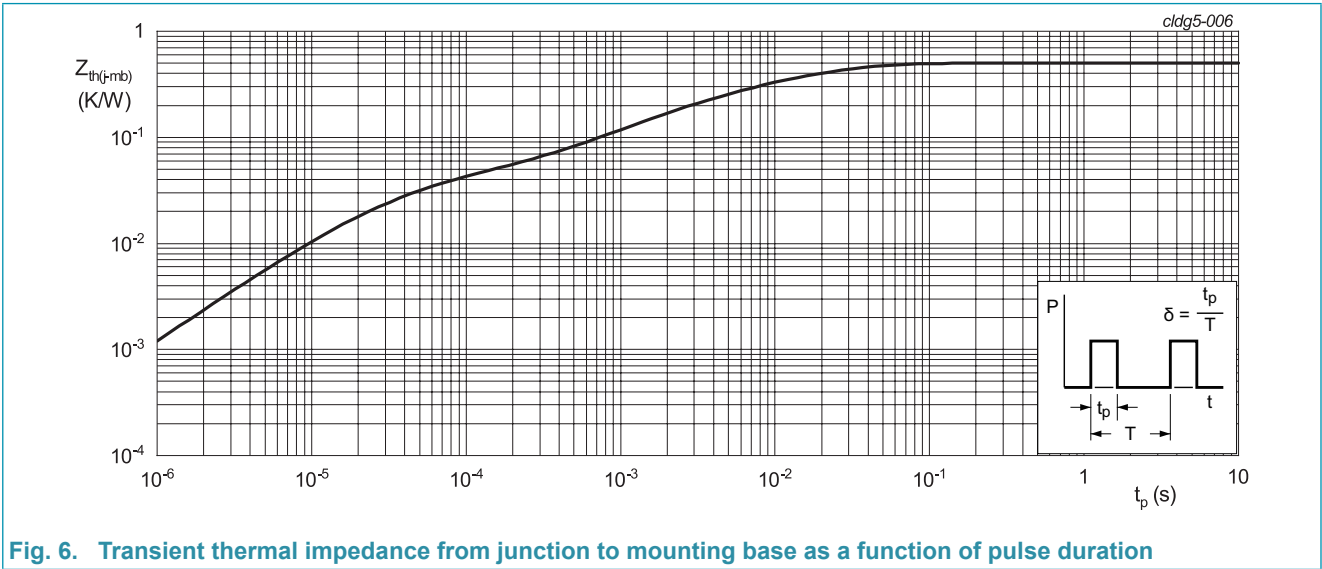
$t_p \leq 10\text{ ms}$
(1) di_T/dt limit

Fig. 5. Non-repetitive peak on-state current as a function of pulse duration; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig 6		-	-	0.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	55	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 7		6	-	15	mA
I _L	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 8		-	-	80	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; Fig. 9		-	-	60	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; Fig. 10		-	1.10	1.30	V
		I _T = 60 A; T _j = 25 °C; Fig. 10		-	1.30	1.50	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11		-	0.6	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C		0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C		-	-	10	μA
		V _D = 800 V; T _j = 150 °C		-	-	1	mA
I _R	reverse current	V _R = 800 V; T _j = 25 °C		-	-	10	μA
		V _R = 800 V; T _j = 150 °C		-	-	1	mA
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 150 °C; exponential waveform; gate open circuit		1000	-	-	V/μs
		V _{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		500	-	-	V/μs
t _{gt}	gate-controlled turn-on time	I _{TM} = 30 A; V _D = 800 V; I _G = 100 mA; dI _G /dt = 5 A/μs; T _j = 25 °C		-	2	-	μs
t _q	commutated turn-off time	V _{DM} = 536 V; T _j = 150 °C; I _{TM} = 30 A; V _R = 25 V; dI _T /dt = 30 A/μs; dV _D /dt = 50 V/μs		-	70	-	μs

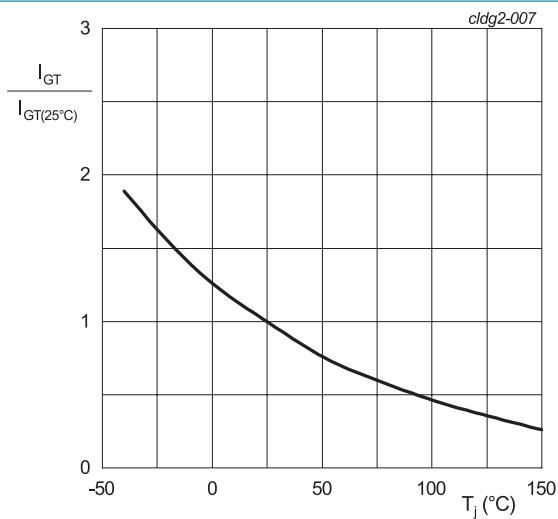


Fig. 7. Normalized gate trigger current as a function of junction temperature

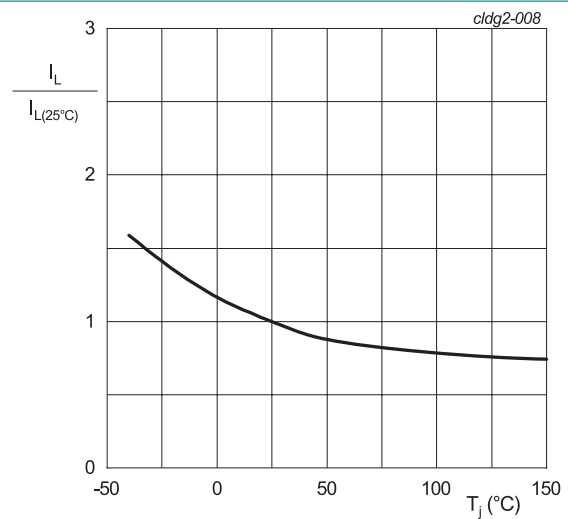


Fig. 8. Normalized latching current as a function of junction temperature

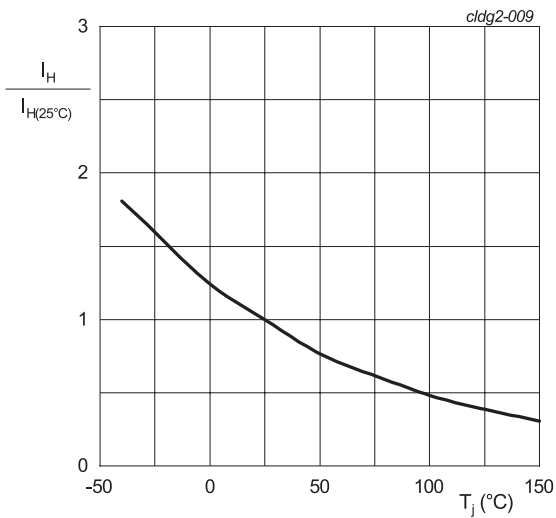
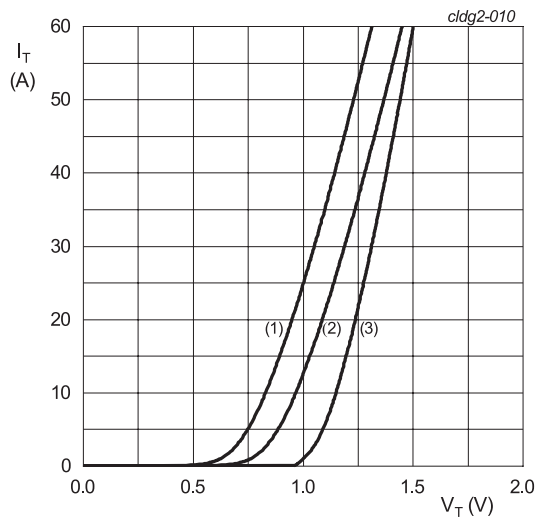


Fig. 9. Normalized holding current as a function of junction temperature



$V_o = 0.994\text{ V}$; $R_s = 0.0096\ \Omega$
(1) $T_j = 150^\circ\text{C}$; typical values
(2) $T_j = 150^\circ\text{C}$; maximum values
(3) $T_j = 25^\circ\text{C}$; maximum values

Fig. 10. On-state current as a function of on-state voltage

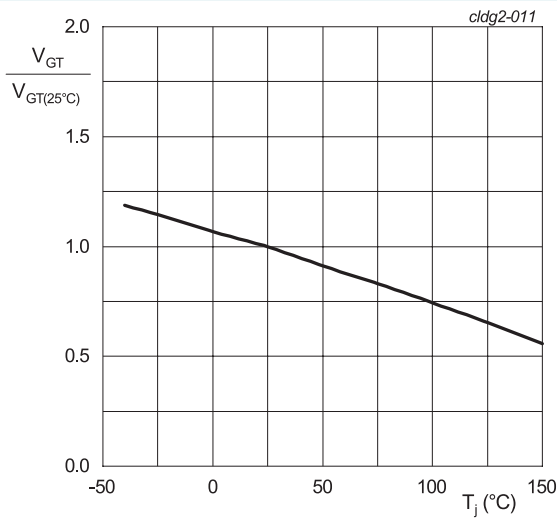
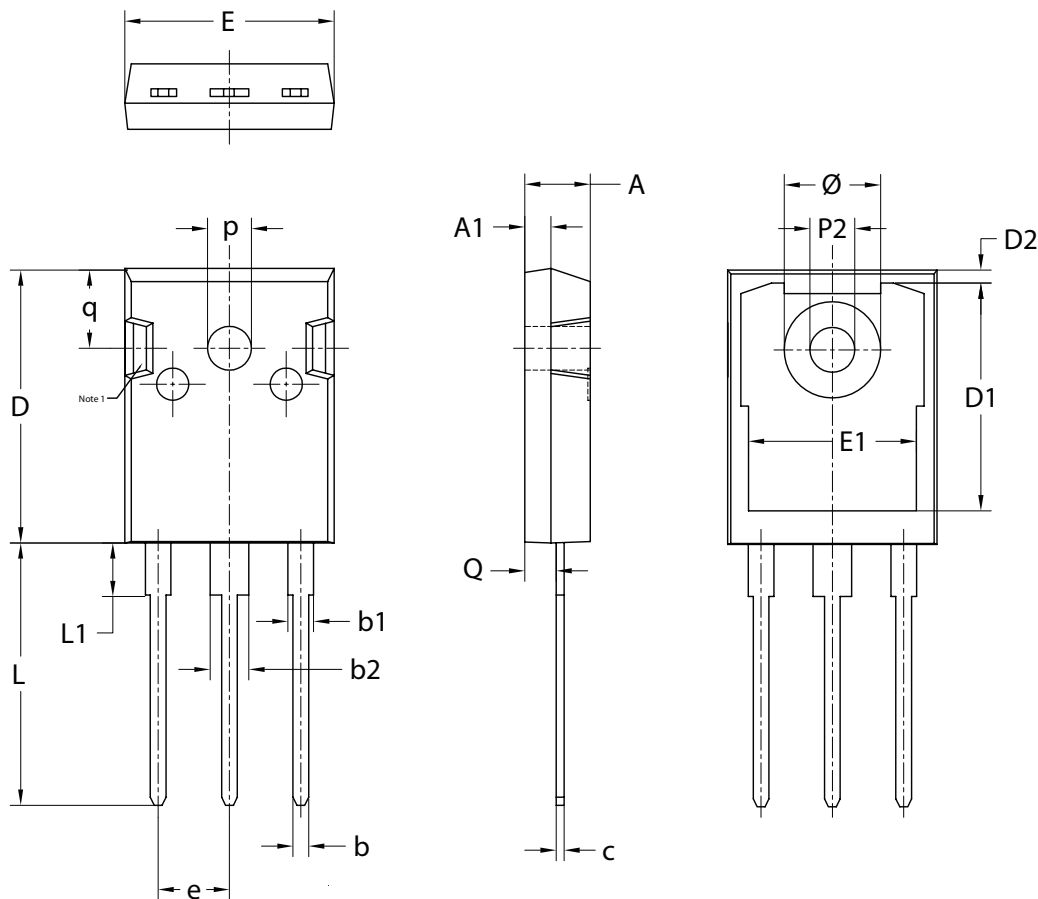


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

11. Package outline

Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3 leads TO-247

TO247



UNIT	A	A1	b	b ₁	b ₂	c	D	D1	D2	E	E1	e	L	L1	P2	p	Q	q	Ø
mm	5.36 4.68	2.10 1.90	1.40 1.00	2.30 1.90	3.30 2.90	0.72 0.48	21.80 20.80	17.10 16.10	1.36 0.80	16.20 15.38	13.52 13.00	5.44 BSC	20.50 19.50	4.35 3.75	3.64 3.24	3.85 3.45	2.60 2.30	6.58 5.99	7.30 7.10

Note:
1. Metal exposed with Sn plating.
2. Dimension D&E do not include mold flash and gate remain

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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